



CYPRESS SEMICONDUCTOR

T-46-23-12

CY7C132/CY7C136
CY7C142/CY7C146

2048 x 8 Dual-Port Static RAM

Features

- 0.8 micron CMOS for optimum speed/power
- Automatic power-down
- TTL-compatible
- Capable of withstanding greater than 200V electrostatic discharge
- Fully asynchronous operation
- MASTER CY7C132/CY7C136 easily expands data bus width to 16 or more bits using SLAVE CY7C142/CY7C146
- BUSY output flag on CY7C132/ CY7C136; BUSY input on CY7C142/CY7C142
- INT flag for port-to-port communication (LCC/PLCC versions)

Functional Description

The CY7C132/CY7C136/CY7C142/CY7C146 are high-speed CMOS 2K by 8 dual-port static RAMs. Two ports are provided permitting independent access to any location in memory. The CY7C132/CY7C136 can be utilized as either a stand-alone 8-bit dual-port static RAM or as a MASTER dual-port RAM in conjunction with the CY7C142/CY7C146 SLAVE dual-port device in systems requiring 16-bit or greater word widths. It is the solution to applications requiring shared or buffered data such as cache memory for DSP, bit-slice, or multiprocessor designs.

Each port has independent control pins; Chip Enable ($\overline{\text{CE}}$), Write Enable ($\overline{\text{WE}}$), and

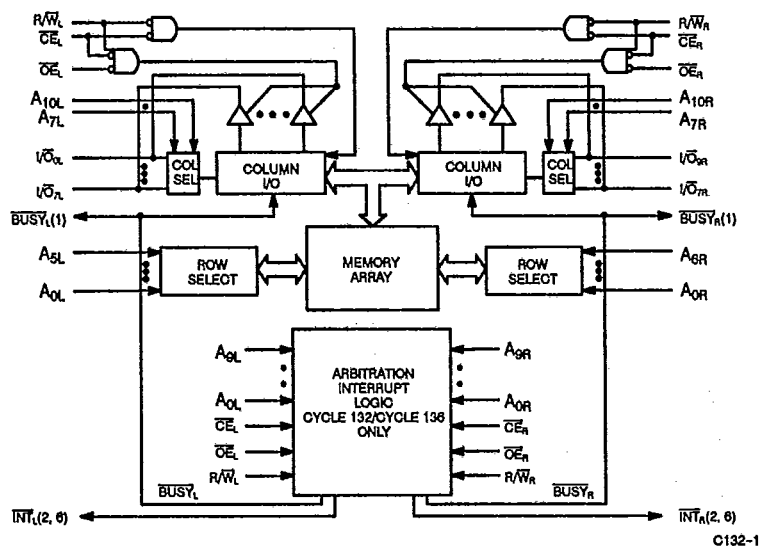
Output Enable (OE). **BUSY** flags are provided on each port. In addition, an interrupt flag (**INT**) is provided on each port of the 52-pin LCC or PLCC versions. **BUSY** signals that the port is trying to access the same location currently be accessed by the other port. On the LCC/PLCC versions, **INT** is an interrupt flag indicating that data has been placed in a unique location by the other port.

An automatic power-down feature is controlled independently on each port by the Chip Enable (CE) pin.

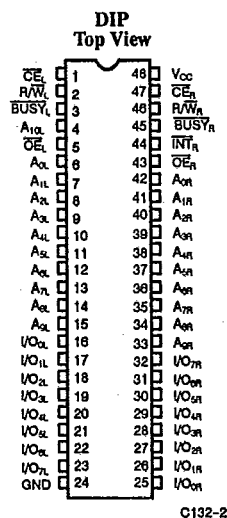
The CY7C132/CY7C142 are available in both 48-pin DIP and 48-pin LCC. The CY7C136/CY7C146 are available in both 52-pin LCC and 52-pin PLCC.

A die coat is used to insure alpha immunity.

Logic Block Diagram



Pin Configuration

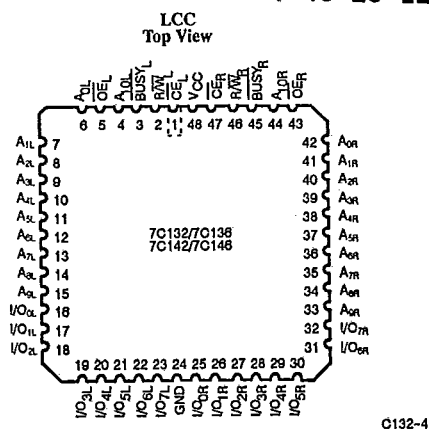
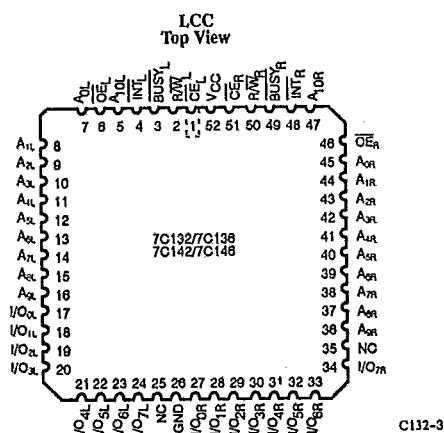


Notes:

1. CY7C132/CY7C136 (Master): BUSY is open drain output and requires pull-up resistor.
CY77C142/CY7C146 (Slave): BUSY is input.
2. Open drain outputs; pull-up resistor required.

Pin Configurations (continued)

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Selection Guide

		7C132-25 7C136-25 7C142-25 7C146-25	7C132-35 7C136-35 7C142-35 7C146-35	7C132-45 7C136-45 7C142-45 7C146-45	7C132-55 7C136-55 7C142-55 7C146-55
Maximum Access Time (ns)		25	35	45	55
Maximum Operating Current (mA)	Commerical	170	120	90	90
	Military		170	120	120
Maximum Standby Current (mA)	Commerical	65	45	35	35
	Military		65	45	45

Shaded area contains preliminary information.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature - 65°C to + 150°C

Ambient Temperature with

Power Applied -55°C to +125°C

Supply Voltage to Ground Potential
(Pin 48 to Pin 24) -0.5V to + 7.0V

DC Voltage Applied to Outputs
in High Z State - 0.5V to + 7.0V

DC Input Voltage - 3.5V to + 7.0V

Output Current into Outputs (Low) 20 mA

Static Discharge Voltage >2001V
(per MIL-STD-883, Method 3015)

Latch-Up Current..... >200 mA

Operating Range

Range	Ambient Temperature	V _{CC}
Commercial	0°C to + 70°C	5V ± 10%
Military ^[3]	- 55°C to + 125°C	5V ± 10%

Electrical Characteristics Over the Operating Range⁽⁴⁾

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Parameters	Description	Test Conditions	7C132-25 7C136-25 7C142-25 7C146-25		7C132-35 7C136-35 7C142-35 7C146-35		7C132-45, 55 7C136-45, 55 7C142-45, 55 7C146-45, 55		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
V _{OH}	Output HIGH Voltage	V _{CC} = Min., I _{OH} = -4.0 mA	2.4		2.4		2.4		V
V _{OL}	Output LOW Voltage	I _{OL} = 4.0 mA		0.4		0.4		0.4	V
		I _{OL} = 16.0 mA ⁽⁵⁾		0.5		0.5		0.5	
V _{IH}	Input HIGH Voltage		2.2		2.2		2.2		V
V _{IL}	Input LOW Voltage			0.8		0.8		0.8	V
I _{IX}	Input Load Current	GND ≤ V _I ≤ V _{CC}	-5	+5	-5	+5	-5	+5	μA
I _{OZ}	Output Leakage Current	GND ≤ V _O ≤ V _{CC} , Output Disabled	-5	+5	-5	+5	-5	+5	μA
I _{OS}	Output Short Circuit Current ⁽⁶⁾	V _{CC} = Max., V _{OUT} = GND		-350		-350		-350	mA
I _{CC}	V _{CC} Operating Supply Current	CE = V _{IL} , Outputs Open, f = f _{MAX}	Com'l	170		120		90	mA
			Mil			170		120	mA
I _{SB1}	Standby Current Both Ports, TTL Inputs	CE _L and CE _R ≥ V _{IH} , f = f _{MAX}	Com'l	65		45		35	mA
			Mil			65		45	mA
I _{SB2}	Standby Current One Port, TTL Inputs	CE _L and CE _R ≥ V _{IH} , Active Port Outputs Open, f = f _{MAX}	Com'l	115		90		75	mA
			Mil			115		90	mA
I _{SB3}	Standby Current Both Ports, CMOS Inputs	Both Ports CE _L and CE _R ≥ V _{CC} - 0.2V, V _{IN} ≥ V _{CC} - 0.2V or V _{IN} ≤ 0.2V, f = 0	Com'l	15		15		15	mA
			Mil			15		15	mA
I _{SB4}	Standby Current One Port, CMOS Inputs	One Port CE _L or CE _R ≥ V _{CC} - 0.2V, V _{IN} ≥ V _{CC} - 0.2V or V _{IN} ≤ 0.2V Active Ports Outputs Open f = f _{MAX}	Com'l	105		85		70	mA
			Mil			105		85	mA

Shaded area contains preliminary information.

Capacitance⁽⁷⁾

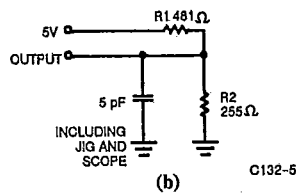
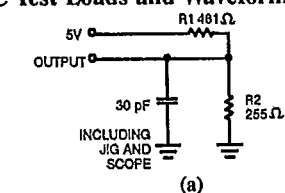
Parameters	Description	Test Conditions	Max.	Units
C _{IN}	Input Capacitance	T _A = 25°C, f = 1 MHz V _{CC} = 5.0V	10	pF
C _{OUT}	Output Capacitance		10	pF

Notes:

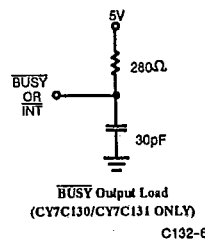
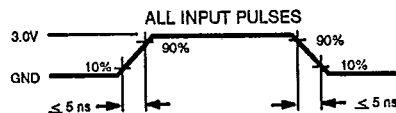
- T_A is the "instant on" case temperature
- See the last page of this specification for Group A subgroup testing information.
- BUSY and INT pins only.
- Duration of the short circuit should not exceed 30 seconds.
- Tested initially and after any design or process changes that may affect these parameters.
- Test conditions assume signal transition times of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V and output loading of the specified I_{OL}/I_{OH}, and 30-pF load capacitance.
- t_{HZOE}, t_{HZCE}, and t_{HZWE} are tested with C_L = 5pF as in part (b) of AC Test Loads. Transition is measured ± 500 mV from steady state voltage.
- At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} for any given device.
- The internal write time of the memory is defined by the overlap of CE LOW and WE LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.



AC Test Loads and Waveforms



Equivalent to: THEVENIN EQUIVALENT
OUTPUT — 187Ω — 1.73V



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Switching Characteristics Over the Operating Range^(4,8)

Writing Characteristics Over the Operating Range

Parameters	Description	7C132-25 7C136-25 7C142-25 7C146-25		7C132-35 7C136-35 7C142-35 7C146-35		7C132-45 7C136-45 7C142-45 7C146-45		7C132-55 7C136-55 7C142-55 7C146-55		Units
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
READ CYCLE										
t _{RC}	Read Cycle Time	25		35		45		55		ns
t _{AA}	Address to Data Valid		25		35		45		55	ns
t _{OHA}	Data Hold from Address Change	0		0		0		0		ns
t _{ACE}	$\overline{CE}$ LOW to Data Valid		30		35		45		25	ns
t _{DOE}	$\overline{OE}$ LOW to Data Valid		15		20		25		25	ns
t _{LZOE}	$\overline{OE}$ LOW to Low Z	3		3		3		3		ns
t _{HZOE}	$\overline{OE}$ HIGH to High Z ^[9]		15		20		20		25	ns
t _{LZCE}	$\overline{CE}$ LOW to Low Z ^[10]	5		5		5		5		ns
t _{HZCE}	$\overline{CE}$ HIGH to High Z ^[9, 10]		15		20		20		25	ns
t _{PU}	$\overline{CE}$ LOW to Power-Up	0		0		0		0		ns
t _{PD}	$\overline{CE}$ HIGH to Power-Down		25		35		35		35	ns
WRITE CYCLE ^[11]										
t _{WC}	Write Cycle Time	25		35		45		55		ns
t _{SCB}	$\overline{CE}$ LOW to Write End	20		30		35		40		ns
t _{AW}	Address Set-Up to Write End	20		30		35		40		ns
t _{HA}	Address Hold from Write End	2		2		2		2		ns
t _{SA}	Address Set-Up to Write Start	0		0		0		0		ns
t _{PWB}	$\overline{WE}$ Pulse Width	20		25		30		30		ns
t _{SD}	Data Set-Up to Write End	15		15		20		20		ns
t _{HD}	Data Hold from Write End	0		0		0		0		ns
t _{HZWB}	$\overline{WE}$ LOW to High Z		15		20		20		25	ns
t _{LZWB}	$\overline{WE}$ HIGH to Low Z	0		0		0		0		ns

Shaded area contains preliminary information.


CY7C132/CY7C136
CY7C142/CY7C146
Switching Characteristics Over the Operating Range^(4,9) (continued)

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Parameters	Description	7C132-25 7C136-25 7C142-25 7C146-25		7C132-35 7C136-35 7C142-35 7C146-35		7C132-45 7C136-45 7C142-45 7C146-45		7C132-55 7C136-55 7C142-55 7C146-55		Units
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
BUSY/INTERRUPT TIMING										
t _{BLA}	BUSY LOW from Address Match		20		20		25		30	ns
t _{BHA}	BUSY HIGH from Address Mismatch ^[12]		20		20		25		30	ns
t _{BLC}	BUSY LOW from CE LOW		20		20		25		30	ns
t _{BHC}	BUSY HIGH from CE HIGH ^[12]		20		20		25		30	ns
t _{PS}	Port Set Up for Priority	5		5		5		5		ns
t _{WB} ^[13]	WE LOW after BUSY LOW	0		0		0		0		ns
t _{WH}	WE HIGH after BUSY HIGH	20		30		35		35		ns
t _{BDD}	BUSY HIGH to Valid Data		25		35		45		45	ns
t _{DDD}	Write Data Valid to Read Data Valid		Note 14		Note 14		Note 14		Note 14	ns
t _{WDD}	Write Pulse to Data Delay		Note 14		Note 14		Note 14		Note 14	ns
INTERRUPT TIMING										
t _{WINS}	WE to INTERRUPT Set Time		25		25		35		45	ns
t _{EINS}	CE to INTERRUPT Set Time		25		25		35		45	ns
t _{INS}	Address to INTERRUPT Set Time		25		25		35		45	ns
t _{OINR}	OE to INTERRUPT Reset Time ^[12]		25		25		35		45	ns
t _{EINR}	CE to INTERRUPT Reset Time ^[12]		25		25		35		45	ns
t _{INR}	Address to INTERRUPT Reset Time ^[12]		25		25		35		45	ns

Shaded area contains preliminary information.

Notes:

12. These parameters are measured from the input signal changing, until the output pin goes to a high-impedance state.

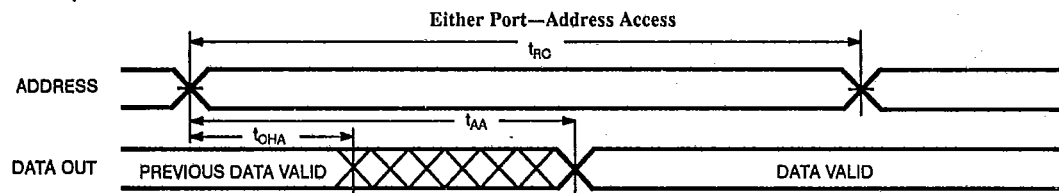
13. CY7C142/CY7C146 only.

14. A write operation on Port A, where Port A has priority, leaves the data on Port B's outputs undisturbed until one access time after one of the following:

- A. $\overline{BUSY}$ on Port B goes HIGH.
- B. Port B's address toggled.
- C. $\overline{CE}$ for Port B is toggled.
- D. $\overline{WE}$ for Port B is toggled.

15. $\overline{WE}$ is HIGH for read cycle.16. Device is continuously selected, $\overline{CS} = V_{IL}$ and $\overline{OE} = V_{IL}$.17. Address valid prior to or coincident with $\overline{CE}$ transition LOW.18. Data I/O pins enter high-impedance state, as shown when $\overline{OE}$ is held LOW during write.

19. LCC version only.

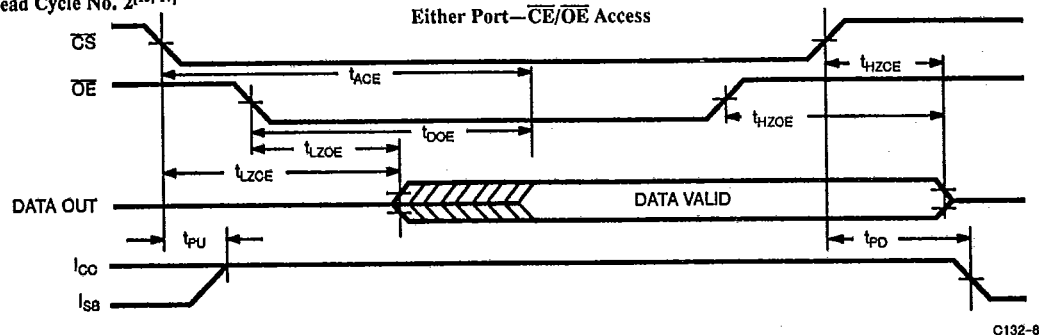
Switching WaveformsRead Cycle No. 1^(15, 16)

C132-7

Switching Waveforms (Continued)

Read Cycle No. 2^[15, 17]

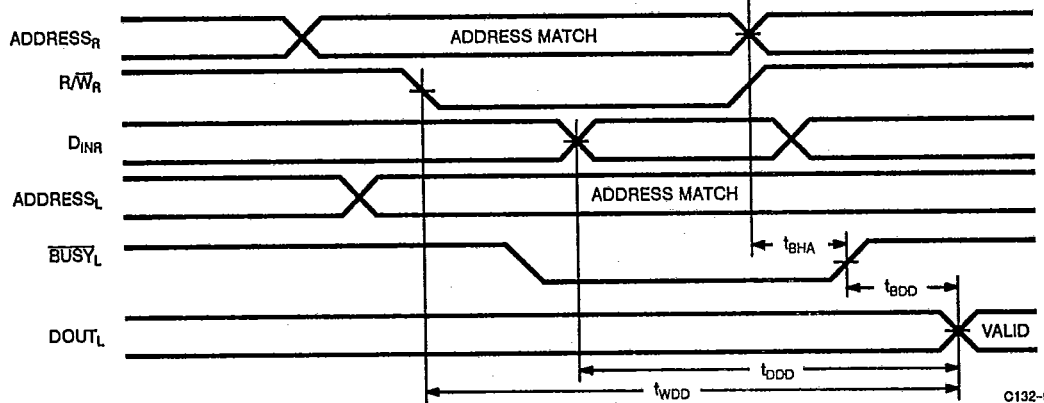
Either Port— $\overline{\text{CE}}/\overline{\text{OE}}$ Access



C132-8

Read Cycle No. 3^[15]

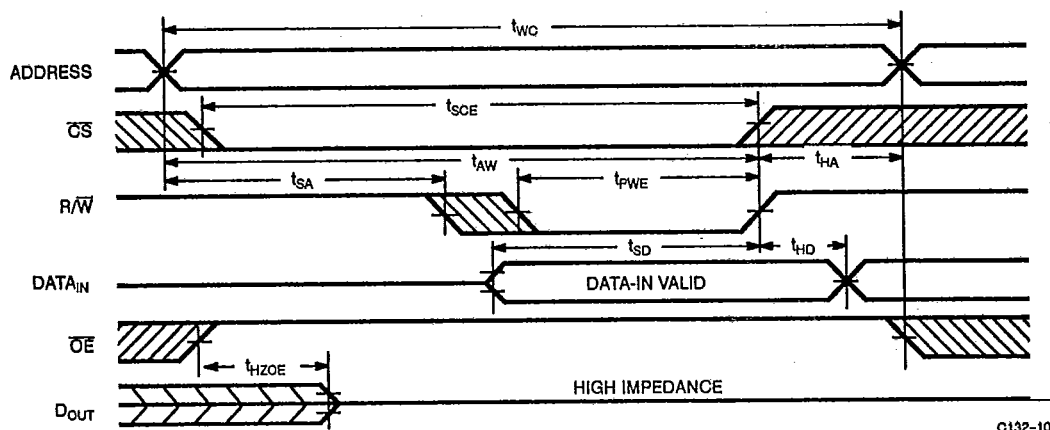
READ with $\overline{\text{BUSY}}$



C132-9

Write Cycle No. 1^[11, 18]

Either Port



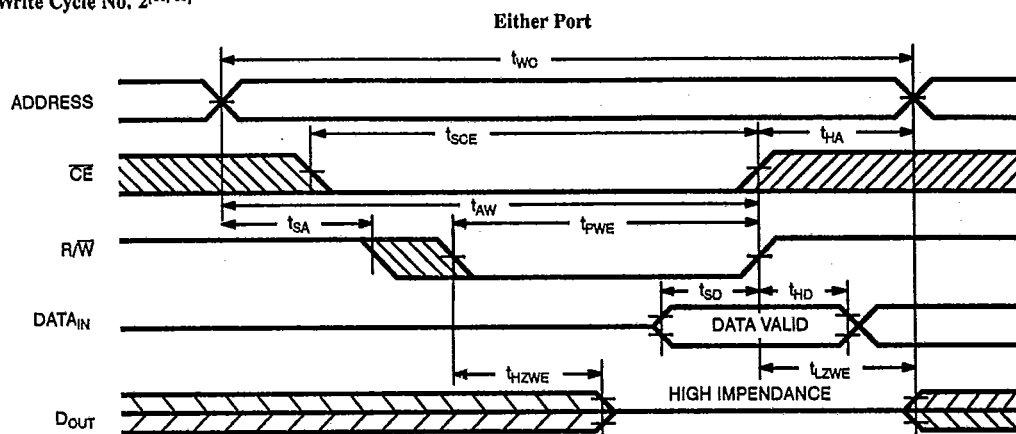
C132-10



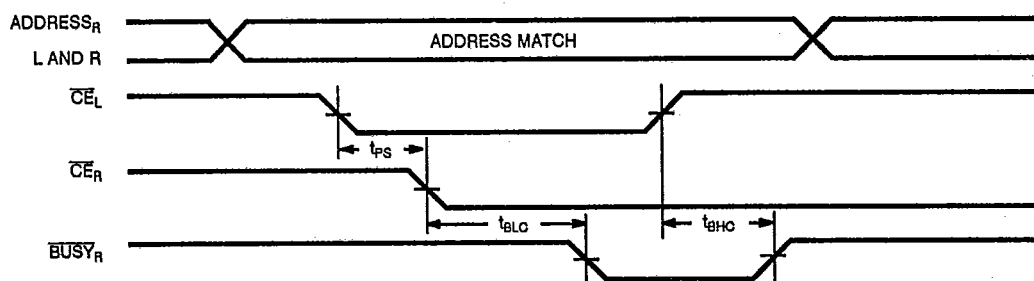
CY7C132/CY7C136
CY7C142/CY7C146

Switching Waveforms (Continued)

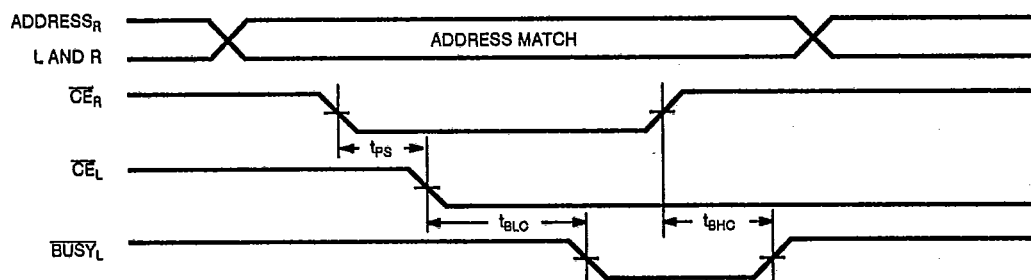
T-46-23-12

Write Cycle No. 2^[11, 18]

Q132-11

Busy Timing Diagram No. 1 ($\overline{CE}$ Arbitration) $\overline{CE}_L$ Valid First:

Q132-12

 $\overline{CE}_R$ Valid First:

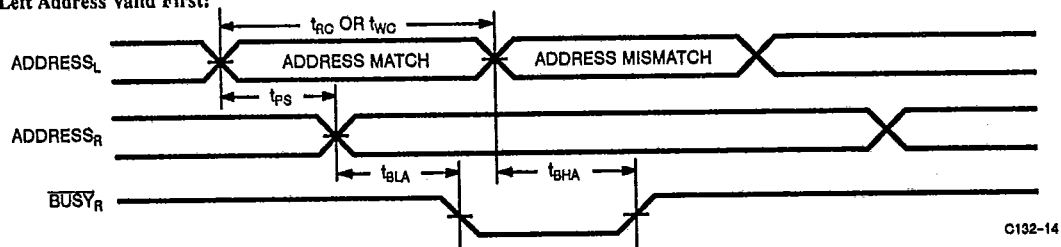
Q132-13



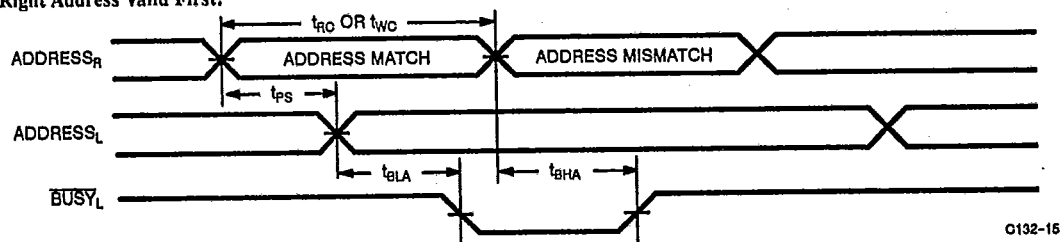
Switching Waveforms (Continued)

Busy Timing Diagram No. 2 (Address Arbitration)

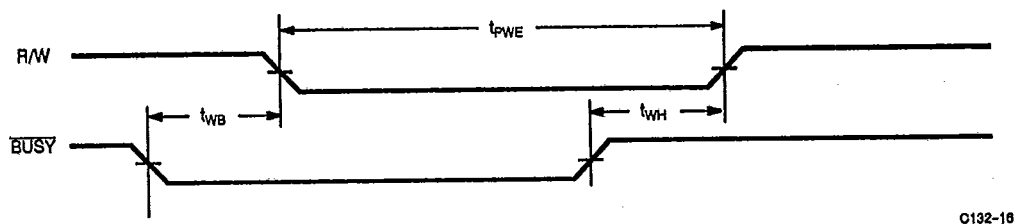
Left Address Valid First:



Right Address Valid First:

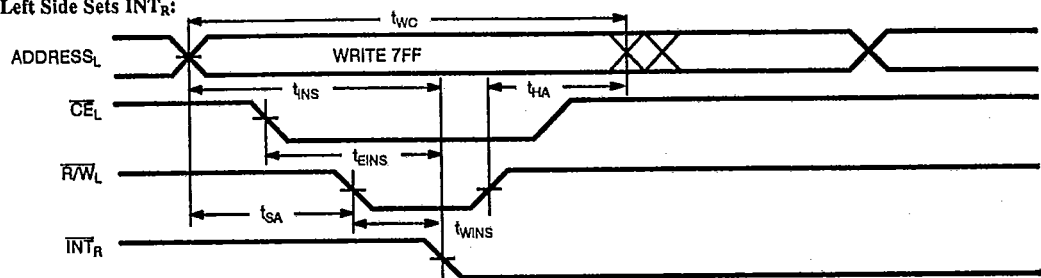


Busy Timing Diagram No. 3

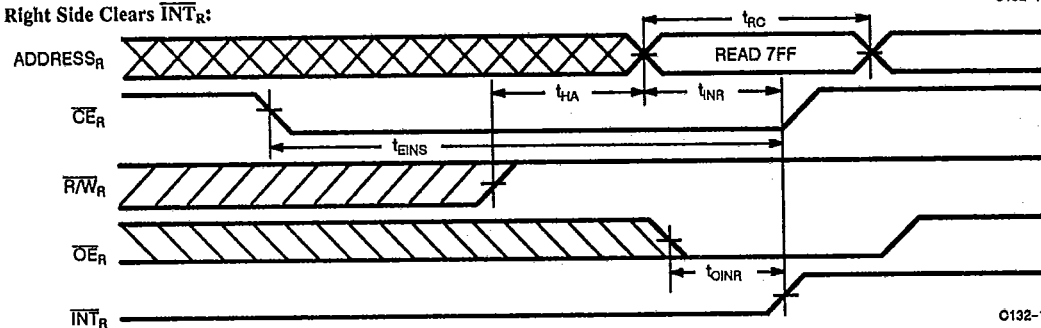
Write with $\overline{BUSY}$ (Slave: CY7C142/CY7C146)



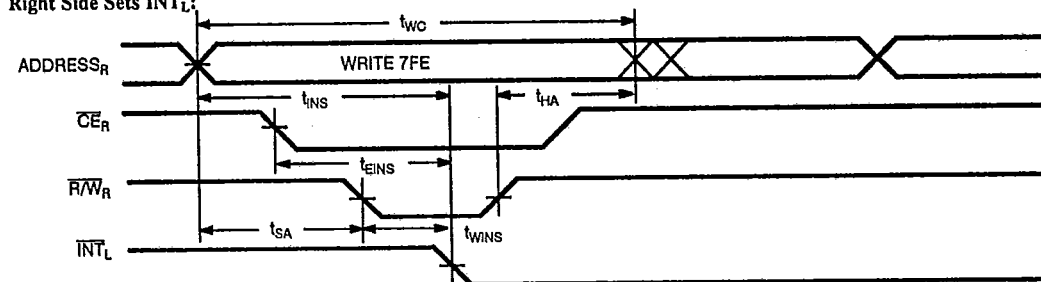
Switching Waveforms (continued)

Interrupt Timing Diagrams⁽¹⁹⁾Left Side Sets $\overline{INT}_R$:

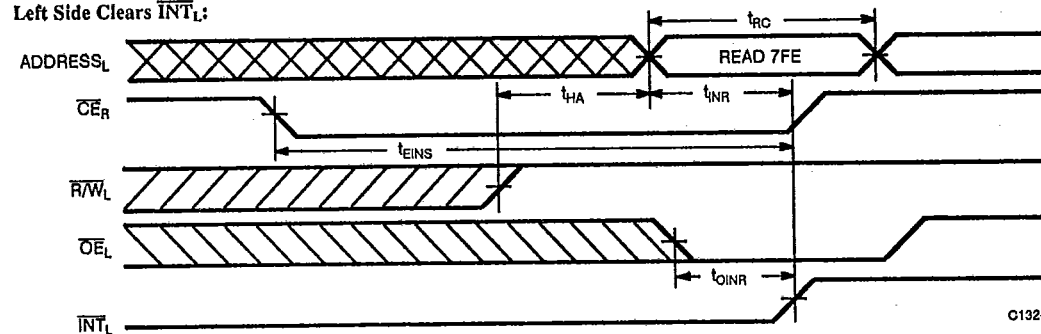
C132-17

Right Side Clears $\overline{INT}_R$:

C132-18

Right Side Sets $\overline{INT}_L$:

C132-19

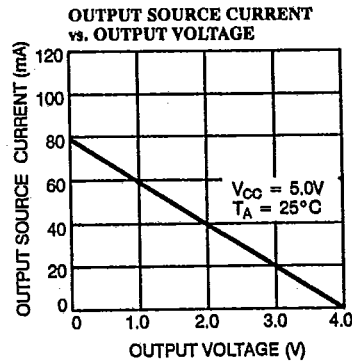
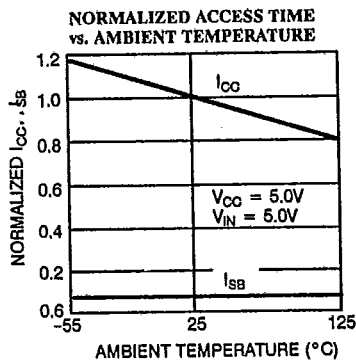
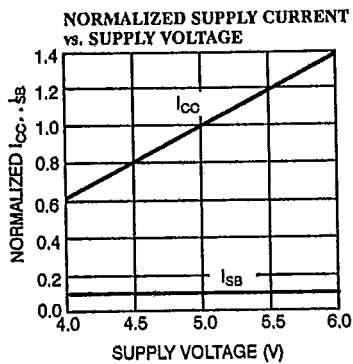
Left Side Clears $\overline{INT}_L$:

C132-20

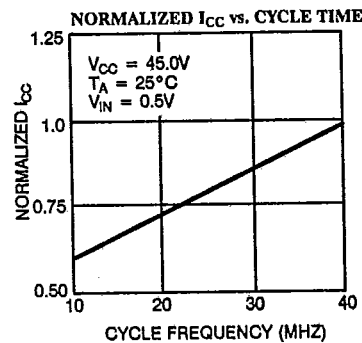
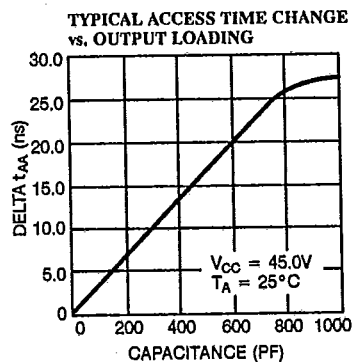
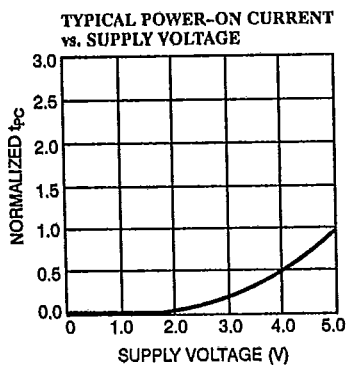
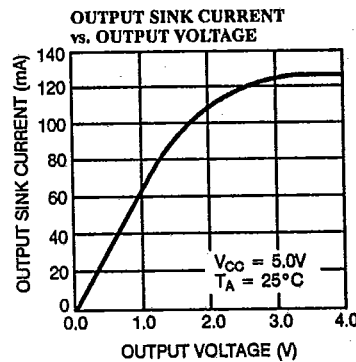
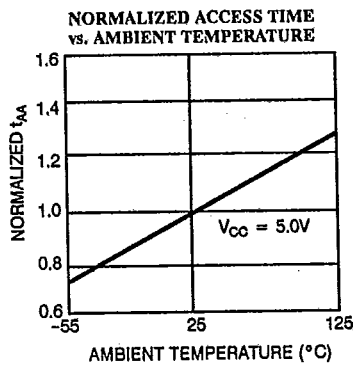
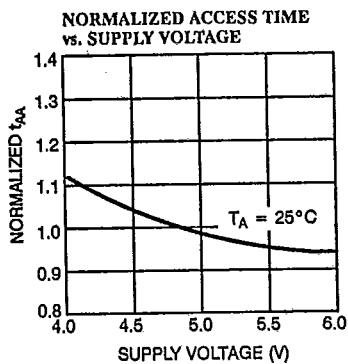


Typical DC and AC Characteristics

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CY7C132/CY7C136

CY7C142/CY7C146

Ordering Information

T-46-23-12

Speed (ns)	Ordering Code	Package Type	Operating Range
25	CY7C132-25PC	P25	Commerical
	CY7C132-25DC	D26	
	CY7C132-25LC	L68	
35	CY7C132-35PC	P25	Commerical
	CY7C132-35DC	D26	
	CY7C132-35LC	L68	
	CY7C132-35DMB	D26	Military
	CY7C132-35LMB	L68	
45	CY7C132-45PC	P25	Commerical
	CY7C132-45DC	D26	
	CY7C132-45LC	L68	
	CY7C132-45DMB	D26	Military
	CY7C132-45LMB	L68	
55	CY7C132-55PC	P25	Commerical
	CY7C132-55DC	D26	
	CY7C132-55LC	L68	
	CY7C132-55DMB	D26	Military
	CY7C132-55LMB	L68	

Speed (ns)	Ordering Code	Package Type	Operating Range
25	CY7C142-25PC	P25	Commerical
	CY7C142-25DC	D26	
	CY7C142-25LC	L68	
35	CY7C142-35PC	P25	Commerical
	CY7C142-35DC	D26	
	CY7C142-35LC	L68	
	CY7C142-35DMB	D26	Military
	CY7C142-35LMB	L68	
45	CY7C142-45PC	P25	Commerical
	CY7C142-45DC	D26	
	CY7C142-45LC	L68	
	CY7C142-45DMB	D26	Military
	CY7C142-45LMB	L68	
55	CY7C142-55PC	P25	Commerical
	CY7C142-55DC	D26	
	CY7C142-55LC	L68	
	CY7C142-55DMB	D26	Military
	CY7C142-55LMB	L68	

Speed (ns)	Ordering Code	Package Type	Operating Range
25	CY7C136-25LC	L69	Commerical
	CY7C136-25JC	J69	
35	CY7C136-35LC	L69	Commerical
	CY7C136-35JC	J69	
	CY7C136-35LMB	L69	Military
45	CY7C136-45LC	L69	Commerical
	CY7C136-45JC	J69	
	CY7C136-45LMB	L69	Military
55	CY7C136-55LC	L69	Commerical
	CY7C136-55JC	J69	
	CY7C136-55LMB	L69	Military

Speed (ns)	Ordering Code	Package Type	Operating Range
25	CY7C146-25LC	L69	Commerical
	CY7C146-25JC	J69	
35	CY7C146-35LC	L69	Commerical
	CY7C146-35JC	J69	
	CY7C146-35LMB	L69	Military
45	CY7C146-45LC	L69	Commerical
	CY7C146-45JC	J69	
	CY7C146-45LMB	L69	Military
55	CY7C146-55LC	L69	Commerical
	CY7C146-55JC	L69	
	CY7C146-55LMB	L69	Military

Shaded area contains preliminary information.



MILITARY SPECIFICATIONS

Group A Subgroup Testing

T-46-23-12

DC Characteristics

Parameters	Subgroups
V _{OH}	1, 2, 3
V _{OL}	1, 2, 3
V _{IH}	1, 2, 3
V _{IL} Max.	1, 2, 3
I _{IX}	1, 2, 3
I _{OZ}	1, 2, 3
I _{OS}	1, 2, 3
I _{CC}	1, 2, 3
I _{SB1}	1, 2, 3
I _{SB2}	1, 2, 3
I _{SB3}	1, 2, 3
I _{SB4}	1, 2, 3

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Switching Characteristics

Parameters	Subgroups
READ CYCLE	
t _{RC}	7, 8, 9, 10, 11
t _{AA}	7, 8, 9, 10, 11
t _{OHA}	7, 8, 9, 10, 11
t _{ACE}	7, 8, 9, 10, 11
t _{DOE}	7, 8, 9, 10, 11
WRITE CYCLE	
t _{WC}	7, 8, 9, 10, 11
t _{SCB}	7, 8, 9, 10, 11
t _{AW}	7, 8, 9, 10, 11
t _{HA}	7, 8, 9, 10, 11
t _{SA}	7, 8, 9, 10, 11
t _{PWE}	7, 8, 9, 10, 11
t _{SD}	7, 8, 9, 10, 11
t _{HD}	7, 8, 9, 10, 11

Parameters	Subgroups
BUSY/INTERRUPT TIMING	
t _{BLA}	7, 8, 9, 10, 11
t _{BHA}	7, 8, 9, 10, 11
t _{BLC}	7, 8, 9, 10, 11
t _{BHC}	7, 8, 9, 10, 11
t _{PS}	7, 8, 9, 10, 11
t _{WINS}	7, 8, 9, 10, 11
t _{EINS}	7, 8, 9, 10, 11
t _{INS}	7, 8, 9, 10, 11
t _{OINR}	7, 8, 9, 10, 11
t _{EINR}	7, 8, 9, 10, 11
t _{INR}	7, 8, 9, 10, 11
BUSY TIMING	
t _{WB} ^[20]	7, 8, 9, 10, 11
t _{WH}	7, 8, 9, 10, 11
t _{BDD}	7, 8, 9, 10, 11
t _{DDD}	7, 8, 9, 10, 11
t _{WDD}	7, 8, 9, 10, 11

Note:

20. CY7C142 only.